

50 V, 100 mA NPN resistor-equipped transistor; R1 = 10 k Ω , R2 = 47 k Ω

25 April 2023

Product data sheet

1. General description

NPN Resistor-Equipped Transistor (RET) in a small SOT883 (SC-101) Surface-Mounted Device (SMD) plastic package.

PNP complement: PDTA114YM

2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- · Digital application in automotive and industrial segments
- Cost-saving alternative for BC847 series in digital applications
- · Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	3.7	4.7	5.7	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	3	
2	GND	ground (emitter)		
3	0	output (collector)		R1
			1 2	GND R2
			Transparent top view DFN1006-3 (SOT883)	sym007

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PDTC114YM		plastic, leadless ultra small package; 3 terminals; 0.35 mm pitch; 1 mm x 0.6 mm x 0.48 mm body	<u>SOT883</u>

7. Marking

Table 4. Marking codes

Type number	Marking code
PDTC114YM	DU

8. Limiting values

Table 5. Limiting values

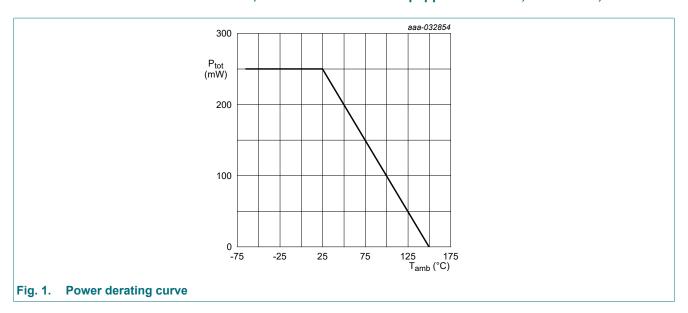
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
VI	input voltage			-6	40	V
Io	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Reflow soldering is the only recommended soldering method.

^[2] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

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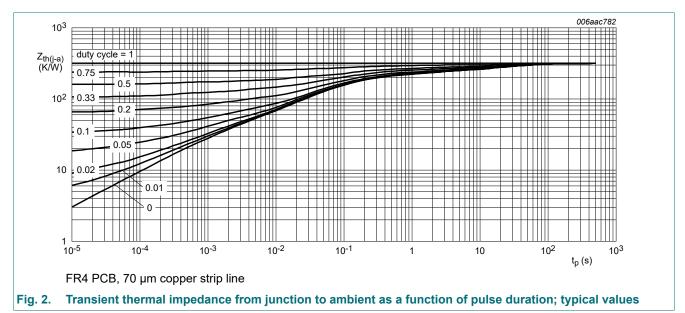


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uily-a)	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W

- [1] Reflow soldering is the only recommended soldering method.
- [2] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



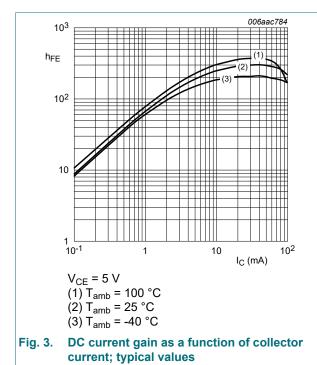
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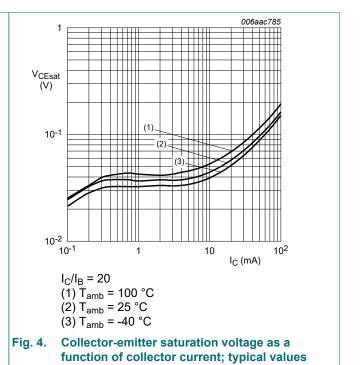
10. Characteristics

Table 7. Characteristics

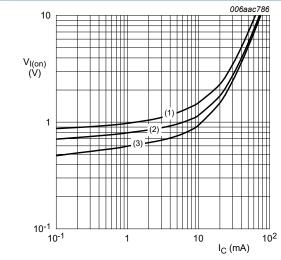
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	150	μΑ
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	0.7	0.5	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 1 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		1.4	0.8	-	V
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	3.7	4.7	5.7	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_{E} = 0 \text{ A}; i_{e} = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	230	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.





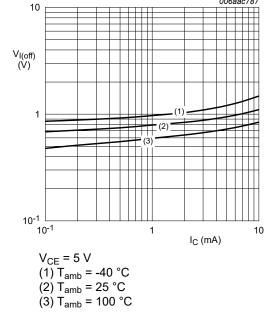
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 $V_{CE} = 0.3 V$

(1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values



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Off-state input voltage as a function of collector current; typical values

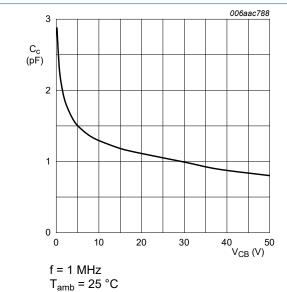
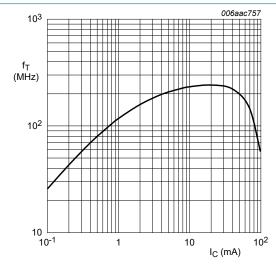


Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values



 V_{CE} = 5 V; T_{amb} = 25 °C

Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

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11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

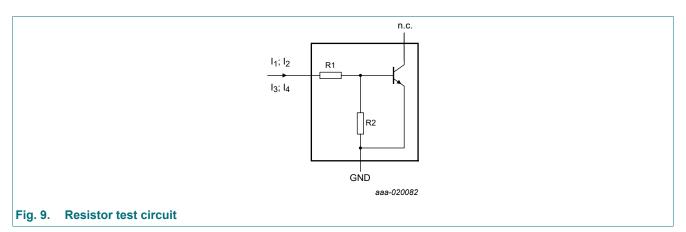
Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



Resistor test conditions

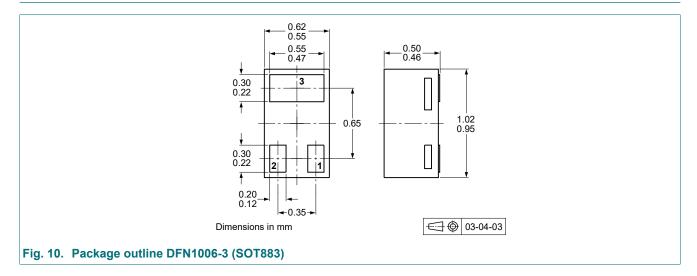
Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions	Test conditions			
			I ₁	l ₂	l ₃	I ₄	
PDTC114YM	10	47	90 μΑ	140 µA	-55 μΑ	-105 µA	

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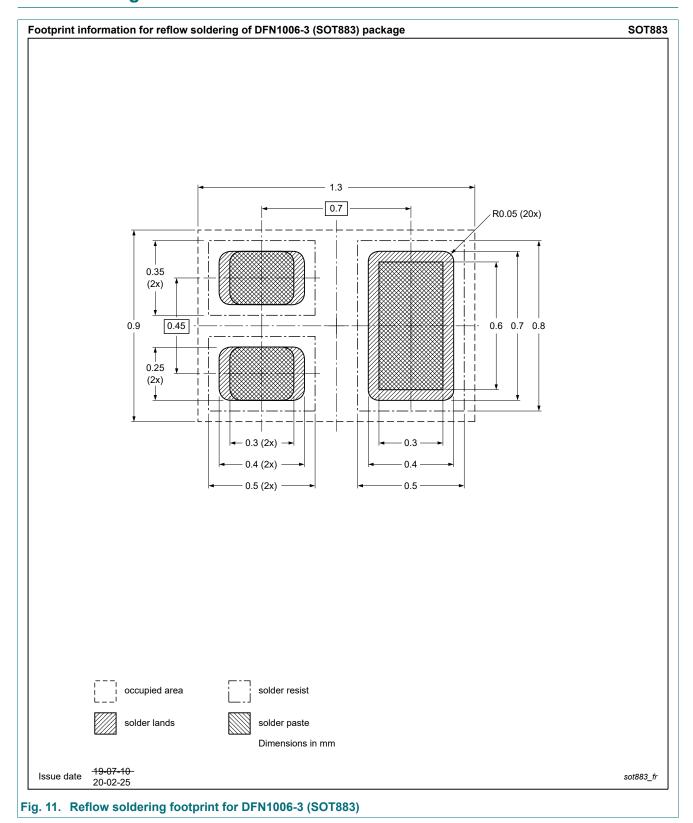
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12. Package outline



50 V, 100 mA NPN resistor-equipped transistor; R1 = 10 k Ω , R2 = 47 k Ω

13. Soldering



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14. Revision history

Table 9. Revision history

Table 9. INEVISION MISIOTY				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PDTC114YM v.8	20230425	Product data sheet	-	PDTC114Y_SER v.7
Modification:	The format or of Nexperia.Legal texts here.Packing information.	sheet splitted to single type dat f this data sheet has been rede ave been adapted to the new of mation removed. cs: Value corrected for I _{CEO} at	esigned to compl company name v	,
PDTC114Y_SER v.7	20111118	Product data sheet	-	PDTC114Y_SERIES v.6
PDTC114Y_SERIES v.6	20040817	Product data sheet	-	PDTC114Y_SERIES v.5
PDTC114Y_SERIES v.5	20040910	Product specification	-	PDTC114Y_SERIES v.4
PDTC114Y_SERIES v.4	20030414	Product specification	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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PDTC114YM

50 V, 100 mA NPN resistor-equipped transistor; R1 = 10 k Ω , R2 = 47 k Ω

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